NSN 5961-00-851-8168

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-851-8168 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current and 10.00 milliamperes source cutoff current blank **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release2887 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**